

2/25/2013



**PRODUCT RELIABILITY REPORT  
FOR**

**MAX31910**

**Maxim Integrated**

**14460 Maxim Dr.  
Dallas, TX 75244**

**Approved by:**

**Sokhom Chum  
MTS, Reliability Engineering**

**Conclusion:**

The following qualification successfully meets the quality and reliability standards required of all Maxim Integrated products:

MAX31910

In addition, Maxim Integrated's continuous reliability monitor program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards. The current status of the reliability monitor program can be viewed at <http://www.maximintegrated.com/qa/reliability/monitor>.

**Device Description:**

A description of this device can be found in the product data sheet. You can find the product data sheet at <http://www.maximintegrated.com/search/parts.mvp>.

**Reliability Derating:**

The Arrhenius model will be used to determine the acceleration factor for failure mechanisms that are temperature accelerated.

$$AfT = \exp((Ea/k) * (1/Tu - 1/Ts)) = tu/ts$$

AfT = Acceleration factor due to Temperature  
tu = Time at use temperature (e.g. 55°C)  
ts = Time at stress temperature (e.g. 125°C)  
k = Boltzmann's Constant (8.617 x 10<sup>-5</sup> eV/°K)  
Tu = Temperature at Use (°K)  
Ts = Temperature at Stress (°K)  
Ea = Activation Energy (e.g. 0.7 eV)

The activation energy of the failure mechanism is derived from either internal studies or industry accepted standards, or activation energy of 0.7eV will be used whenever actual failure mechanisms or their activation energies are unknown. All deratings will be done from the stress ambient temperature to the use ambient temperature.

An exponential model will be used to determine the acceleration factor for failure mechanisms, which are voltage accelerated.

$$AfV = \exp(B * (Vs - Vu))$$

AfV = Acceleration factor due to Voltage  
Vs = Stress Voltage (e.g. 7.0 volts)  
Vu = Maximum Operating Voltage (e.g. 5.5 volts)  
B = Constant related to failure mechanism type (e.g. 1.0, 2.4, 2.7, etc.)

The Constant, B, related to the failure mechanism is derived from either internal studies or industry accepted standards, or a B of 1.0 will be used whenever actual failure mechanisms or their B are unknown. All deratings will be done from the stress voltage to the maximum operating voltage. Failure rate data from the operating life test is reported using a Chi-Squared statistical model at the 60% or 90% confidence level (Cf).

The failure rate, Fr, is related to the acceleration during life test by:

$$Fr = X / (ts * AfV * AfT * N * 2)$$

X = Chi-Sq statistical upper limit  
N = Life test sample size

Failure Rates are reported in FITs (Failures in Time) or MTTF (Mean Time To Failure). The FIT rate is related to MTTF by:

$$MTTF = 1/Fr$$

NOTE: MTTF is frequently used interchangeably with MTBF.

The calculated failure rate for this device/process is:

**FAILURE RATE:**                      **MTTF (YRS):**                      **7502**                      **FITS:**                      **15.2**  
**DEVICE HOURS:**                      **60220066**                      **FAILS:**                      **0**

Only data from Operating Life or similar stresses are used for this calculation.

The parameters used to calculate this failure rate are as follows:

**Cf: 60%**                      **Ea: 0.8**                      **B: 0**                      **Tu: 25 °C**                      **Vu: 36 Volts**

The reliability data follows. At the start of this data is the device information. The next section is the detailed reliability data for each stress. The reliability data section includes the latest data available and may contain some generic data. **Bold** Product Number denotes specific product data.

**Device Information:**

Process: Maxim SA Fab S45  
 Passivation: SiN/SiO2  
 Die Size: 80 x 95  
 Number of Transistors: 6550  
 Interconnect: Aluminum / 0.5% Copper  
 Gate Oxide Thickness: 140Å

**ESD HBM**

DESCRIPTION	DATE	CODE/PRODUCT/LOT	CONDITION	READPOIN	QTY	FAILS	FA#
ESD SENSITIVITY	1218	<b>MAX31910</b>	ZJ276928FA JESD22-A114 HBM 500 VOLTS	1	PUL'S	5	0
ESD SENSITIVITY	1218	<b>MAX31910</b>	ZJ276928FA JESD22-A114 HBM 1000 VOLTS	1	PUL'S	5	0
ESD SENSITIVITY	1218	<b>MAX31910</b>	ZJ276928FA JESD22-A114 HBM 1500 VOLTS	1	PUL'S	5	0
ESD SENSITIVITY	1218	<b>MAX31910</b>	ZJ276928FA JESD22-A114 HBM 2000 VOLTS	1	PUL'S	5	0
ESD SENSITIVITY	1218	<b>MAX31910</b>	ZJ276928FA JESD22-A114 HBM 4000 VOLTS	1	PUL'S	5	0
<b>Total:</b>						<b>0</b>	

**LATCH-UP**

DESCRIPTION	DATE	CODE/PRODUCT/LOT	CONDITION	READPOIN	QTY	FAILS	FA#
LATCH-UP I	1218	<b>MAX31910</b>	ZJ276928FA JESD78A, I-TEST 25C 100mA		6	6	No FA
LATCH-UP V	1218	<b>MAX31910</b>	ZJ276928FA JESD78A, V-SUPPLY TEST 25C		6	0	
<b>Total:</b>						<b>6</b>	

**OPERATING LIFE**

DESCRIPTION	DATE	CODE/PRODUCT/LOT	CONDITION	READPOIN	QTY	FAILS	FA#
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HIGH TEMP OP LIFE	0943	MAX31190	WJ051035AB 125C, 3.6 VOLTS	192	HRS	45	0
HIGH TEMP OP LIFE	1105	DS3920	ZJ163071AB 135C, 75V (V8)	192	HRS	77	0
HIGH TEMP OP LIFE	1218	<b>MAX31910</b>	ZJ276928FA 135C, 36V (V8)	192	HRS	80	0
HIGH TEMP OP LIFE	1231	MAX31865	ZJ381729AB- 125C, 3.7V (PSA)	192	HRS	80	0
<b>Total:</b>							<b>0</b>

**FAILURE RATE:                    MTTF (YRS):                    7502                    FITS:                    15.2**  
**DEVICE HOURS:                    60220066                    FAILS:                    0**

Cumulative monitor data for the S4 Process results in a FIT Rate of 0.13 @ 25C and 2.31 55C (0.8eV, 60% UCL).

MAX31910 passes +/- 100mA and overvoltage per JEDEC JESD78, except pin 5VOUT which passes - 50mA and fails at -75mA. This pin will always have a 4.7uF and a 10-100nF caps to ground in all applications and is therefore not a likely source of latch-up per Annex A of JESD78.